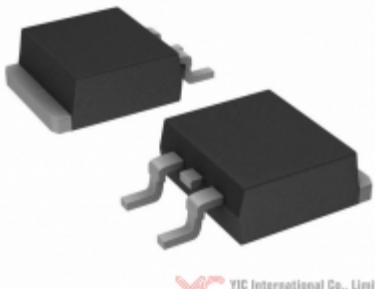


	<p>SQM110P04-04L-GE3</p>
	<p>Hersteller-Teilenummer: SQM110P04-04L-GE3</p>
	<p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p>
	<p>Teil der Beschreibung: MOSFET P-CH 40V 120A TO263</p>
	<p>Datenblätter:  SQM110P04-04L-GE3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 10990 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	SQM110P04-04L-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 40V 120A TO263
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	10990 pcs Stock
detaillierte Beschreibung	P-Channel 40V 120A (Tc) 375W (Tc) Surface Mount
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	TO-263 (D2Pak)
Verlustleistung (max)	375W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	120A (Tc)
Rds On (Max) @ Id, Vgs	4 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	330nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	13980pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

SQM110P04-04L-GE3 ist neu im Original, Suche SQM110P04-04L-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SQM110P04-04L-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SQM110P04-04L-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SQM110N05-06L_GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 55V 110A TO263</p>	 <p>SQM110P06-8M9L_GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 110A TO263</p>	 <p>SQM110P06-07L-GE3 VISHAY SQM110P06-07L-GE3 VISHAY</p>	 <p>SQM110N06-04L-GE3 VB SQM110N06-04L-GE3 VB</p>
 <p>SQM110P04-04L-GE3 Vishay / Siliconix MOSFET P-CH 40V 120A TO263</p>	 <p>SQM110N05-06L_GE3 Vishay / Siliconix MOSFET N-CH 55V 110A TO263</p>	 <p>SQM120N03-1M5L-GE3 VISHAY SQM120N03-1M5L-GE3 VISHAY</p>	 <p>SQM120N02-1M3L_GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 120A TO263</p>

heiße Teile

Mehr

0402YC183MAT2A	ADM811RARTZ-REEL7	C1005X6S1H473M050BB	CC0402DRNPO8BN100	CL05B103MA5N9NC
EMIF07-USB01F2A7	GAL16V8D-25LP	L9605013TR	LV8415CB-TE-L-H	OMAPL138BZCEA3D
QRS1240T30	S-8241ABKMC-T2	SQM100N04-2M7	SQM100N04-3M5-GE3	SQM100N10-10-GE3
D SQM110N04-02L-GE3	SQM110N04-03-GE3	SQM110N04-03L-GE3	SQM110N05-06L-GE3	SQM110N06-04L-GE3
SQM110N06-06-GE3	SQM110P04-04L-GE3	SQM120N03-1M5L-GE3	SQM120N04-02L-GE3	SQM120N04-03-GE3
SQM120N04-03L-GE3	SQM120N04-04-GE3	D SQM120N04-1M7L-GE3	SQM120N04-1m8-GE3	SQM120N04-1M9-GE3
SQM120N04-2m1-GE3	D SQM120N06-04L-GE3	SQM120N06-06-GE3	SQM120N08-05-GE3	SQM120N10-09-GE3
SQM25N15-52-GE3	SQM40N10-30-GE3	SQM40N15-38-GE3	SQM47N10-24L-GE3	SQM50N04-4m0L-GE3
SQM50N04-4M1-GE3	SQM50N04-5m0-GE3	SQM50P03-07-GE3	D SQM60N06-15-GE3	SQM85N03-06P-GE3
SQM85N10-10-GE3	SQM85N15-19-GE3	STT253GK12	UCC283TD-3	XC9503B093AR

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